SUPPLEMENTARY INFORMATION

Strain induced band modulation and excellent stability, transport and optical properties of Penta-MP₂ (M = Ni, Pd and Pt) monolayers

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Structure	Strain	E (eV)		ф (eV)		E _g (eV)	
		without	with	without	with	without	with
NiP ₂	Unstrained	-32.79	-32.83	5.30	5.30	0.06	0.06
	Uniaxial (12%)	-31.42	-31.46	5.05	5.22	0.35	0.35
	Biaxial (06%)	-31.82	-31.86	5.08	5.23	0.33	0.35
PdP ₂	Unstrained	-32.53	-32.55	5.14	5.14	0.15	0.15
	Uniaxial (09%)	-31.75	-31.78	5.09	5.05	0.26	0.26
	Biaxial (06%)	-31.63	-31.65	5.13	5.10	0.35	0.35
PtP ₂	Unstrained	-35.52	-35.53	5.39	5.40	0.06	0.06
	Uniaxial (12%)	-33.80	-33.82	5.43	5.42	0.44	0.44
	Biaxial (09%)	-33.08	-33.09	5.43	5.45	0.60	0.60

Table S1: The calculated total energy (E), work function (ϕ) and PBE bandgap (E_g) with and without consideration of the dipole correction.



Fig. S1: Band structures of the Penta-NiP₂ monolayer under different uniaxial and biaxial strains. The first and second rows represent the uniaxial and biaxial strains, respectively, whereas black color band diagrams indicate the band structure respective to the maximum energy gap under uniaxial and biaxial strains.



Fig. S2: Band structures of the Penta-PdP₂ monolayer under different uniaxial and biaxial strains. The first and second rows represent the uniaxial and biaxial strains, respectively, whereas black color band diagrams indicate the band structure respective to the maximum energy gap under uniaxial and biaxial strains.



Fig. S3: Band structures of the Penta-PtP₂ monolayer under different uniaxial and biaxial strains. The first and second rows represent the uniaxial and biaxial strains, respectively, whereas black color band diagrams indicate the band structure respective to the maximum energy gap under uniaxial and biaxial strains.



Fig. S4: Phonon diagram of the Penta- NiP_2 monolayer under different uniaxial and biaxial strains. The first and second rows represent the uniaxial and biaxial strains, respectively.



Fig. S5: Phonon diagram of the Penta-PdP $_2$ monolayer under different uniaxial and biaxial strains. The first and second rows represent the uniaxial and biaxial strains, respectively.



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